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February 2007

FDS6690A

FDS6690A

Single N-Channel, Logic-Level, PowerTrench[®] MOSFET

General Description

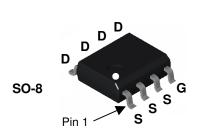
This N-Channel Logic Level MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.

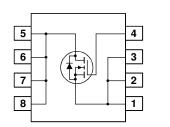
These devices are well suited for low voltage and battery powered applications where low in-line power loss and fast switching are required.



Features

- + 11 A, 30 V. $R_{DS(ON)} = 12.5 \text{ m}\Omega @ V_{GS} = 10 \text{ V}$ $R_{DS(ON)} = 17.0 \text{ m}\Omega @ V_{GS} = 4.5 \text{ V}$
- Fast switching speed
- Low gate charge
- High performance trench technology for extremely low R_{DS(ON)}
- High power and current handling capability





Absolute Maximum Ratings T_A=25°C unless otherwise noted

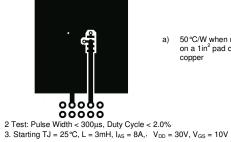
Symbol	Parameter			Ratings	Units
V _{DSS}	Drain-Source	ce Voltage	30	V	
V _{GSS}	Gate-Source Voltage			±20	V
ID	Drain Curre	nt – Continuous	(Note 1a)	11	A
		– Pulsed		50	
PD	Power Diss	ipation for Single Operation	ON (Note 1a)	2.5	W
			(Note 1b)	1.0	
E _{AS}	Single Pulse Avalanche Energy (Note 3)			96	mJ
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C
Therma	l Charac	teristics			
R _{θJA}	Thermal Resistance, Junction-to-Ambient (Note 1a)				°C/W
R _{eJA}	Thermal Resistance, Junction-to-Ambient (Note 1b)			125	
R _{eJC}	Thermal Resistance, Junction-to-Case (Note 1)			25	
Packag	e Markin	g and Ordering	Information		·
Device Marking		Device	Reel Size	Tape width	Quantity
FDS6690A		FDS6690A	13"	12mm	2500 units

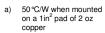
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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V$, $I_D = 250 \mu A$	30			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		25		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24 V$, $V_{GS} = 0 V$			1	μA
		$V_{DS} = 24 V, V_{GS} = 0 V, T_{J} = 55^{\circ}C$			10	μA
I _{GSS}	Gate-Body Leakage	$V_{GS}=\pm 20~V, ~~V_{DS}=0~V$			±100	nA
On Chara	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, \qquad I_D = 250 \ \mu A$	1	1.9	3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		-5		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance	$ \begin{array}{ll} V_{GS} = 10 \ V, & I_D = 11 \ A \\ V_{GS} = 4.5 \ V, & I_D = 10 \ A \\ V_{GS} = 10 \ V, \ I_D = 11 \ A, \ T_J = 125^\circ C \end{array} $		9.8 12.0 13.7	12.5 17.0 22.0	mΩ
I _{D(on)}	On-State Drain Current	$V_{GS} = 10 \text{ V}, \qquad V_{DS} = 5 \text{ V}$	50			Α
g _{FS}	Forward Transconductance	$V_{\text{DS}} = 5 \text{ V}, \qquad I_{\text{D}} = 11 \text{ A}$		48		S
Dynamic	Characteristics					
C _{iss}	Input Capacitance	pacitance $V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V},$		1205		pF
Coss	Output Capacitance	f = 1.0 MHz		290		pF
C _{rss}	Reverse Transfer Capacitance			115		pF
R _G	Gate Resistance	$V_{\text{GS}} = 15 \text{ mV}, f = 1.0 \text{ MHz}$		2.4		Ω
Switchin	g Characteristics (Note 2)					
t _{d(on)}	Turn-On Delay Time	$V_{\text{DD}} = 15 \text{ V}, \qquad I_{\text{D}} = 1 \text{ A},$		9	19	ns
tr	Turn–On Rise Time	$V_{GS} = 10 \text{ V}, \qquad R_{GEN} = 6 \Omega$		5	10	ns
t _{d(off)}	Turn-Off Delay Time			28	44	ns
t _f	Turn–Off Fall Time			9	19	ns
Qg	Total Gate Charge	$V_{DS} = 15 V$, $I_{D} = 11 A$,		12	16	nC
Q _{gs}	Gate–Source Charge	$V_{GS} = 5 V$		3.4		nC
Q _{gd}	Gate-Drain Charge			4.0		nC
Drain-So	ource Diode Characteristics	and Maximum Ratings				
ls	Maximum Continuous Drain-Source	e Diode Forward Current			2.1	Α
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 \ V,$ $I_{S} = 2.1 \ A \ (Note 2)$		0.74	1.2	V
t _{rr}	Diode Reverse Recovery Time	- I _F = 11 A, d _{iF} /d _t = 100 A/μs		24		nS
Q _{rr}	Diode Reverse Recovery Charge	$I_F = II A, u_{iF}/u_t = I 00 A/\mu S$	1	27		nC

Notes:

1. R_{8JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $\rm R_{\theta JC}$ is guaranteed by design while $\rm R_{\theta CA}$ is determined by the user's board design.





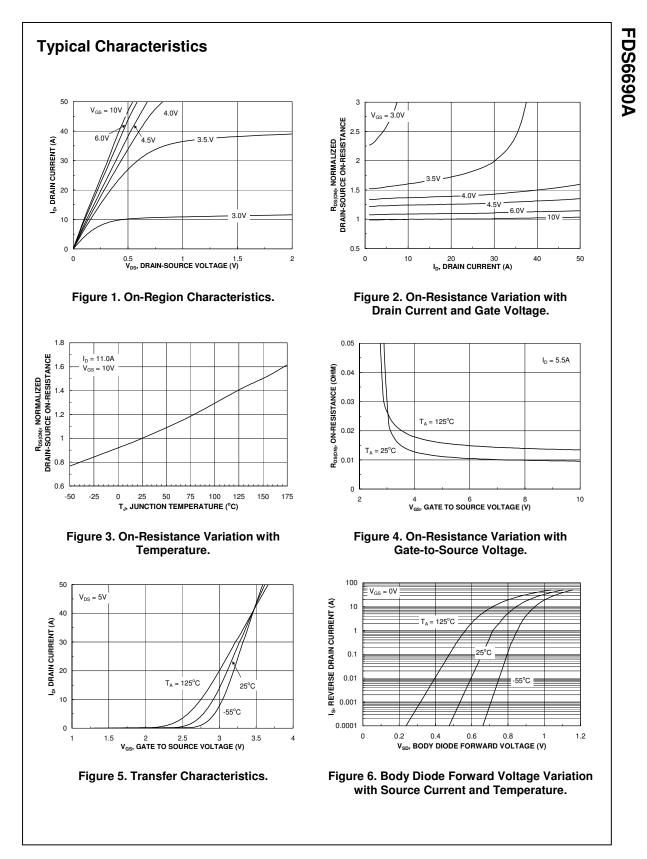


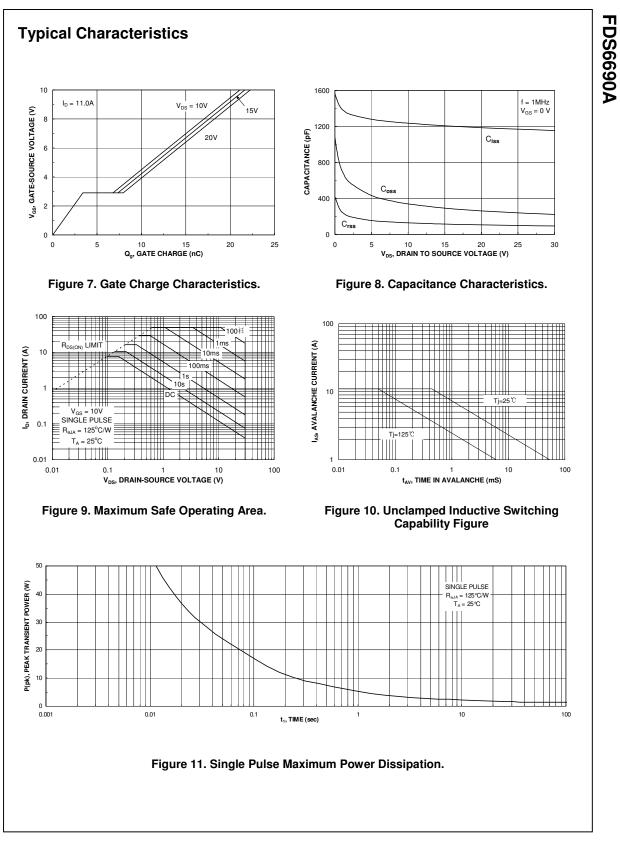
b) 125°C/W when mounted on a minimum pad.

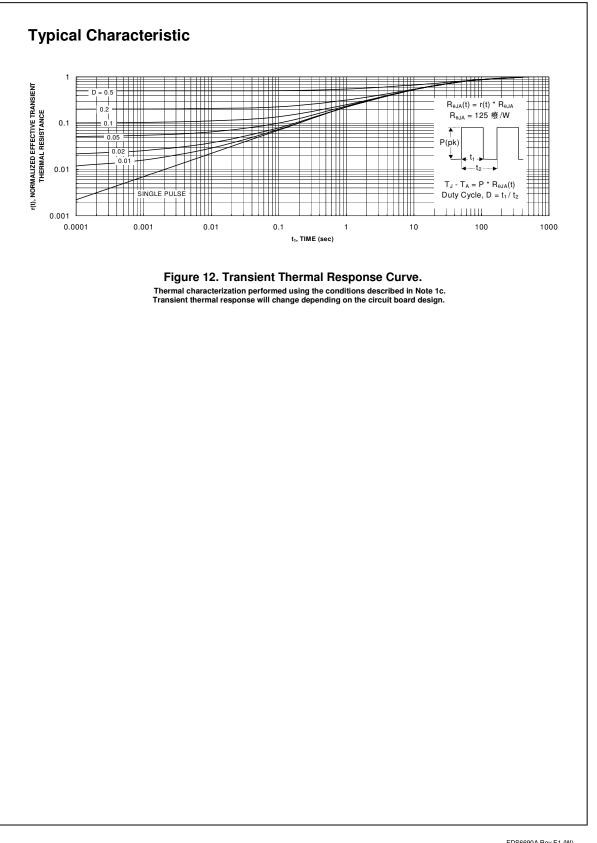
Scale 1 : 1 on letter size paper

FDS6690A Rev E1 (W)

FDS6690A







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